Diode Semiconductor Device - Page 1 of 1



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Inclosure	e Material:
Glass and	d metal
Overall L	ength:
0.450 incl	hes
Terminal	Length:
0.375 incl	hes
Mounting	g Facility Quantity:
1	
Mounting	g Method:
Terminal	and threaded stud
Features	Provided:
Hermetica	ally sealed case
Overall V	Vidth Across Flats:
Between	0.667 inches and 0.687 inches
Thread S	ize:
0.190 incl	hes
Semicon	ductor Material:
Silicon	
Voltage F	Rating In Volts Per Characteristic:
100.0 rev	verse voltage, peak
Current F	Rating Per Characteristic:
85.00 am	peres source cutoff current preset
Thread S	Series Designator:
Unf	
Terminal	Type And Quantity:
1 threade	d stud and 1 tab, solder lug
Shelf Life	2:
N/a	
Unit Of N	leasure:
Demilitar	ization:
No	
Fiig:	
A110a0	